








	<h2>SI1330EDL-T1-GE3</h2>
	<p><b>Hersteller-Teilenummer:</b> <a href="#">SI1330EDL-T1-GE3</a></p> <p><b>Hersteller / Marke:</b> <a href="#">Vishay / Siliconix</a></p> <p><b>Teil der Beschreibung:</b> MOSFET N-CH 60V 240MA SC-70-3</p> <p><b>Datenblätter:</b>  <a href="#">SI1330EDL-T1-GE3.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 60450 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	<a href="#">SI1330EDL-T1-GE3</a>
Hersteller	<a href="#">Vishay / Siliconix</a>
Beschreibung	MOSFET N-CH 60V 240MA SC-70-3
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a>
Teilstatus	60450 pcs Stock
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	SC-70, SOT-323
Supplier Device-Gehäuse	SC-70-3
Verlustleistung (max)	280mW (Ta)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	60V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	240mA (Ta)
Rds On (Max) @ Id, Vgs	2.5 Ohm @ 250mA, 10V
VGS (th) (Max) @ Id	2.5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	0.6nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	-
Antriebsspannung (Max Rds On, Min Rds On)	3V, 10V
Vgs (Max)	±20V
Verpackung	Tape & Reel (TR)






SI1330EDL-T1-GE3 ist neu im Original, Suche SI1330EDL-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI1330EDL-T1-GE3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI1330EDL-T1-GE3: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>SI1400DL-T1-E3</b> Vishay / Siliconix MOSFET N-CH 20V 1.6A SC70-6</p>	 <p><b>SI1317DL-T1-GE3</b> Vishay / Siliconix MOSFET P-CH 20V 1.4A SC70</p>	 <p><b>SI1317DL-T1-GE3</b> Electro-Films (EFI) / Vishay MOSFET P-CH 20V 1.4A SC70</p>	 <p><b>SI1330EDL-T1-E3</b> Electro-Films (EFI) / Vishay MOSFET N-CH 60V 240MA SOT323-3</p>
 <p><b>SI13726CB</b> SILICON SILICON BGA</p>	 <p><b>SI1400DL-T1-GE3</b> Vishay / Siliconix MOSFET N-CH 20V 1.6A SC-70-6</p>	 <p><b>SI1400DL-T1-E3</b> Electro-Films (EFI) / Vishay MOSFET N-CH 20V 1.6A SC70-6</p>	 <p><b>SI1400DL-T1</b> VISHAY SI1400DL-T1 VISHAY</p>

### heiße Teile

Mehr

 SI1305LT-T1-E3	 SI1306DL	 SI1307-DL-T1-E3	 SI1307DL	 SI1307DL-T1
 SI1307DL-T1-E3	 SI1307DL-T1-E3	 SI1307DL-T1-GE3	 SI1307DL-T1-GE3	 SI1307EDL
 SI1307EDL-T1-E3	 SI1307EDL-T1-E3	 SI1307EDL-T1-GE3	 SI1307EDL-T1-GE3	 SI1308EDL
 SI1308EDL-T1-GE3	 SI1308EDL-T1-GE3	 SI13132CNU	 SI1315DL-T1-GE3	 SI1315DL-T1-GE3
 SI1317DL-T1-GE3	 SI1317DL-T1-GE3	 SI1330EDL-T1-E3	 SI1330EDL-T1-E3	 SI1330EDL-T1-GE3
 SI1400DL-T1	 SI1400DL-T1-E3	 SI1400DL-T1-E3	 SI1400DL-T1-GE3	 SI1400DL-T1-GE3
 SI1401EDH-T1-GE3	 SI1401EDH-T1-GE3	 SI1402DH-T1-GE3	 SI1402DH-T1-GE3	 SI1403BDL-T1-E3
 SI1403BDL-T1-E3	 SI1403BDL-T1-GE3	 SI1403BDL-T1-GE3	 SI1403CDL-T1-GE3	 SI1403CDL-T1-GE3
 SI1403DL	 SI1403DL-T1	 SI1403DL-T1-E3	 SI1403DL-T1-GE3	 SI1404BDH-T1-E3
 SI1404BDH-T1-E3	 SI1404DH-T1	 SI1404DH-T1-E3	 SI1404DH-T1-GE3	 SI1404DL-T1-GE3

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